

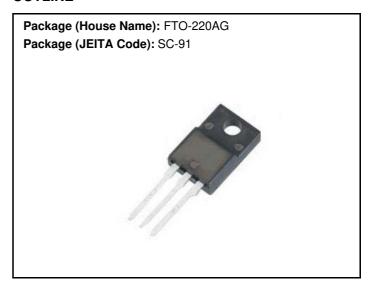
# **P42F6EN**

# Power MOSFETs 60V, 42A, N-channel

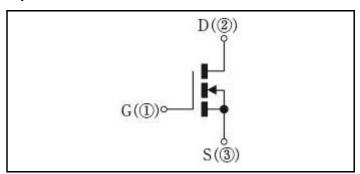
#### **Feature**

- N-channel
- Isolated Package
- Low Ron
- 10V Gate Drive
- · Low Capacitance
- · Pb free terminal
- RoHS:Yes

### **OUTLINE**



# **Equivalent circuit**



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperrature	Tstg		-55 to 150	°C
Channel tempertature	Tch		150	°C
Drain-source voltage	$V_{DSS}$		60	٧
Gate-source voltage	$V_{GSS}$		±20	٧
Continuous drain current(DC)	I <sub>D</sub>		42	А
Continuous drain current(Peak)	I <sub>DP</sub>	Pulse width 10µs, duty=1/100	168	А
Total power dissipation	P <sub>T</sub>		40	W
Single avalanche current	I <sub>AS</sub>	Starting Tch=25°C Tch≦150°C	34	А
Single avalanche energy	E <sub>AS</sub>	Starting Tch=25°C Tch≦150°C	60	mJ
Dielectric strenght	Vdis	Terminals to case, AC1min	2	kV
Mounting torque	TOR	(Recommended torque : 0.3N⋅m)	0.5	N∙m

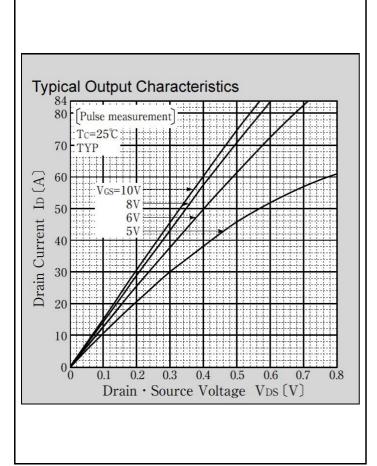
<sup>\* :</sup> See the original Specifications

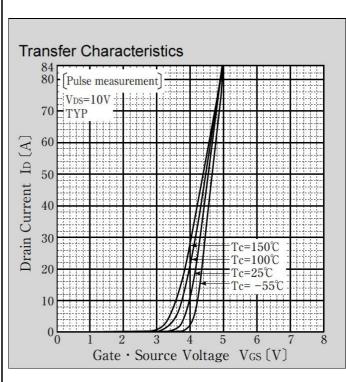
# **Electrical Characteristics** (unless otherwise specified : Tc=25°C)

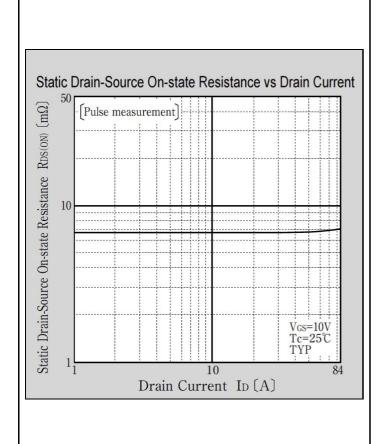
Item	Symbol	Conditions		Ratings		
			MIN	TYP	MAX	Unit
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	60			٧
Zero gate voltage drain current	I <sub>DSS</sub>	VDS=60V, VGS=0V			1	μA
Gate-source leakage current	I <sub>GSS</sub>	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	9fs	ID=21A, VDS=10V	14			S
Static drain-source on-state resistance	R <sub>DS(ON)</sub>	ID=21A, VGS=10V		0.0067	0.0084	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	$V_{SD}$	IS=42A, VGS=0V			1.5	٧
Thermal resistance	Rth(j-c)	Junction to case			3.12	°C/W
Total gate charge	Qg	VDD=48V, VGS=10V, ID=42A		47		nC
Gate to source charge	Qgs	VDD=48V, VGS=10V, ID=42A		12		nC
Gate to drain charge	Qgd	VDD=48V, VGS=10V, ID=42A		16		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		2540		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		170		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		350		pF
Turn-on delay time	td(on)	ID=21A, RL=1.43Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		11		ns
Rise time	tr	ID=21A, RL=1.43Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		22		ns
Turn-off delay time	td(off)	ID=21A, RL=1.43Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		21		ns
Fall time	tf	ID=21A, RL=1.43Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		4		ns
Diode reverse recovery time	trr	IF=42A, VGS=0V, di/dt=100A/μs		45		ns
Diode reverse recovery charge	Qrr	IF=42A, VGS=0V, di/dt=100A/μs		71		nC

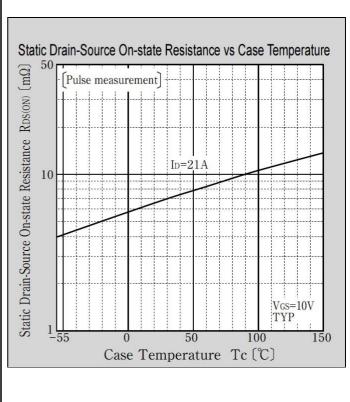
<sup>\*</sup> :See the original Specifications

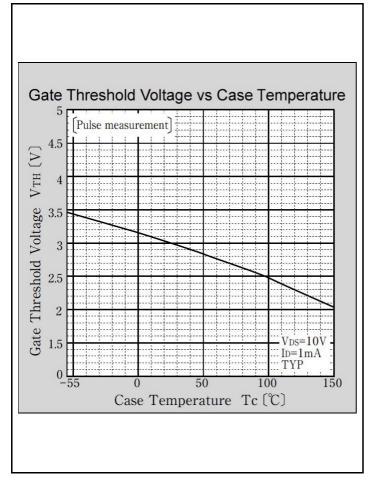
# **CHARACTERISTIC DIAGRAMS**

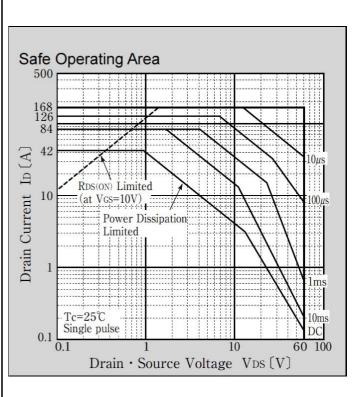


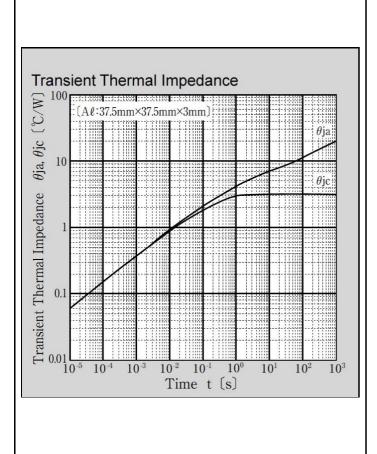


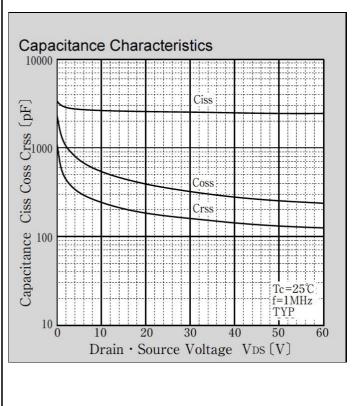


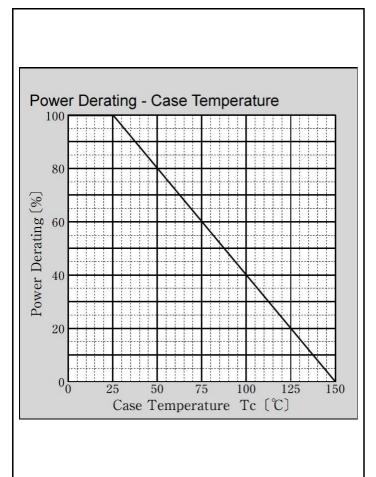


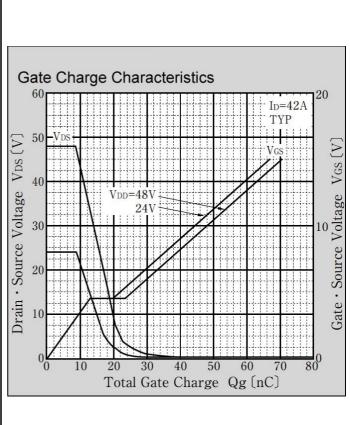


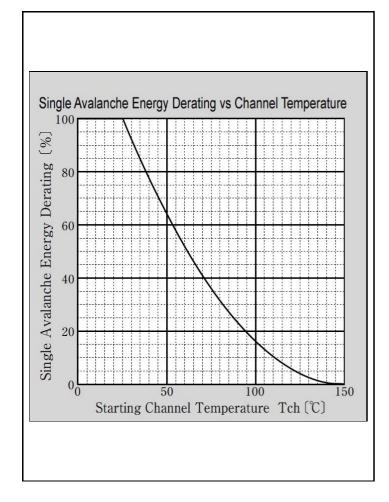










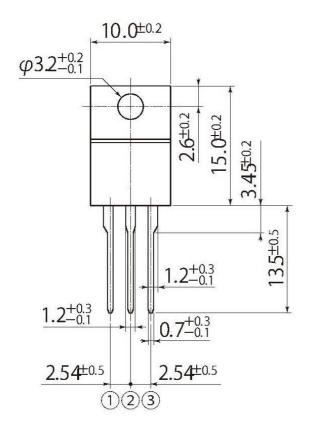


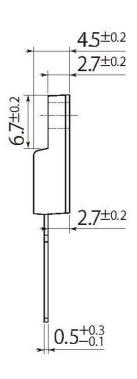
unit:mm

scale: 2/1

**J8** 

JEDEC Code	-		
JEITA Code	SC-91		
House Name	FTO-220AG(3pin)		





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